

# **MOSFET** – Power, Single P-Channel

-30 V, -5 A, 59 m $\Omega$ 

# MCH6341

#### **Features**

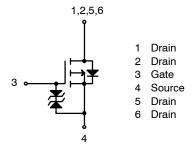
- Low R<sub>DS</sub>(on)
- 4 V Drive
- ESD Diode Protected Gate
- This Device is Pb-Free and Halogen Free and RoHS Compliant

#### **ABSOLUTE MAXIMUM RATINGS** (Ta = 25°C)

Parameter	Symbol	Conditions	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$		-30	V
Gate-to-Source Voltage	$V_{GSS}$		±20	٧
Drain Current (DC)	I <sub>D</sub>		-5	Α
Drain Current (Pulse)	I <sub>DP</sub>	PW ≤ 10 μs, duty cycle ≤ 1%	-20	Α
Power Dissipation	P <sub>D</sub>	When mounted on ceramic substrate (1200 mm <sup>2 x</sup> 0.8 mm)	1.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

V <sub>DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
-30 V	59 mΩ @ –10 V	-5 A
	100 mΩ @ –4.5 V	
	115 mΩ @ –4 V	



#### **ELECTRICAL CONNECTION P-CHANNEL**



SC-88FL / MCPH6 CASE 419AS

#### **MARKING DIAGRAM**



YQ = Specific Device Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MCH6341-TL-W	MCPH6 (Pb–Free, Halogen Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## MCH6341

## **ELECTRICAL CHARACTERISTICS** (Ta = 25°C)

			Value			
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	$I_D = -1$ mA, $V_{GS} = 0$ V	-30	-	_	V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1	μΑ
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±10	μΑ
Gate Threshold Voltage	V <sub>GS</sub> (th)	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-1.2	-	-2.6	V
Forward Transconductance	9 <sub>FS</sub>	$V_{DS} = -10 \text{ V}, I_D = -3 \text{ A}$	2.8	4.8	_	S
Static Drain-to-Source On-State	R <sub>DS</sub> (on)1	$I_D = -3 \text{ A}, V_{GS} = -10 \text{ V}$	-	45	59	mΩ
Resistance	R <sub>DS</sub> (on)2	I <sub>D</sub> = -1.5 A, V <sub>GS</sub> = -4.5 V	-	71	100	mΩ
	R <sub>DS</sub> (on)3	$I_D = -1.5 \text{ A}, V_{GS} = -4 \text{ V}$	-	82	115	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V, f = 1 MHz	-	430	_	pF
Output Capacitance	Coss		_	105	_	pF
Reverse Transfer Capacitance	Crss		_	75	_	pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit	-	7.5	_	ns
Rise Time	t <sub>r</sub>		_	26	_	ns
Turn-OFF Delay Time	t <sub>d</sub> (off)		_	45	_	ns
Fall Time	t <sub>f</sub>		_	35	_	ns
Total Gate Charge	Qg	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -5.0 \text{ A}$	_	10	_	nC
Gate-to-Source Charge	Qgs		-	2.0	-	nC
Gate-to-Drain "Miller" Charge	Qgd		-	2.5	-	nC
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = -5 A, V <sub>GS</sub> = 0 V	-	-0.87	-1.5	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

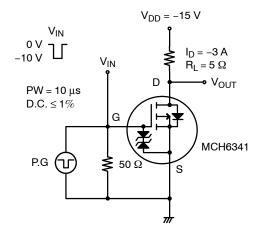
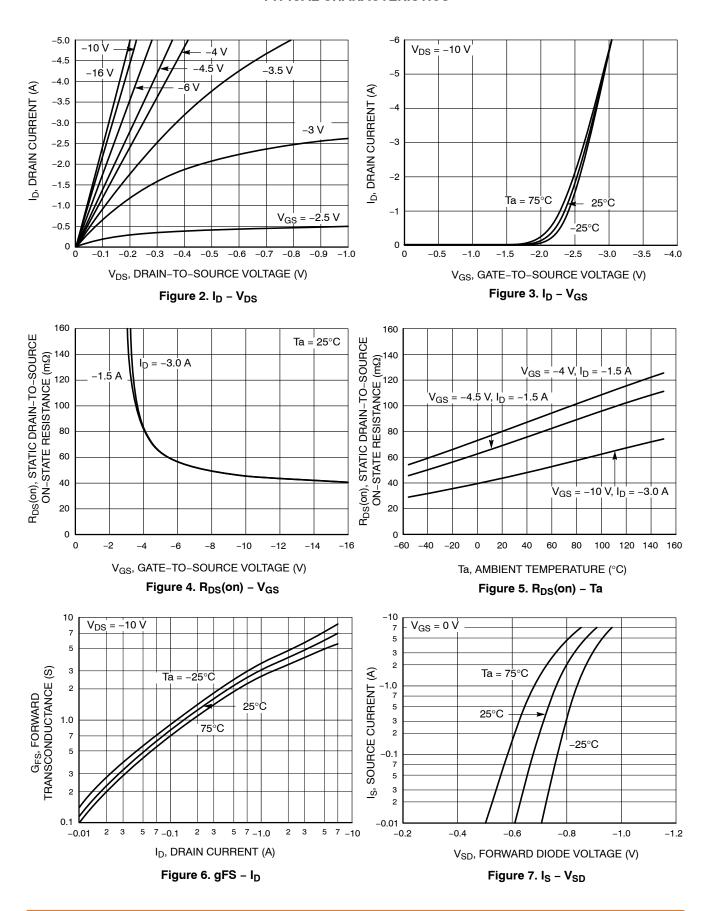


Figure 1. Switching Time Test Circuit

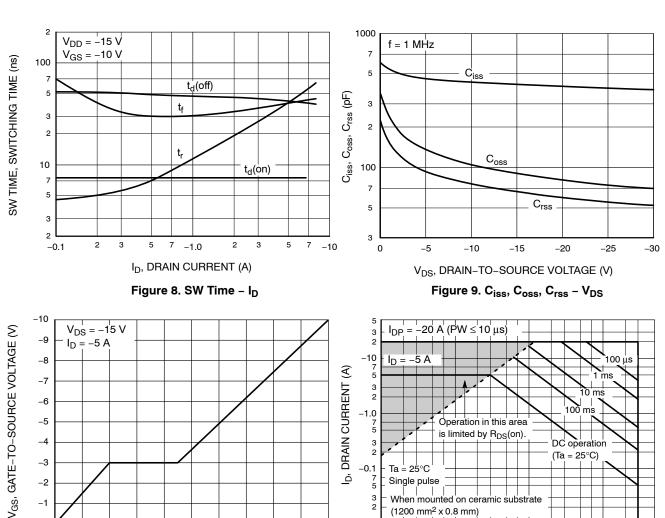
#### MCH6341

#### **TYPICAL CHARACTERISTICS**

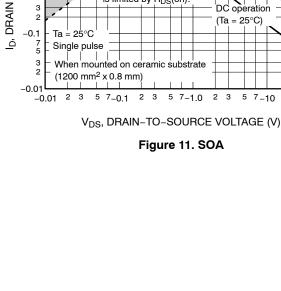


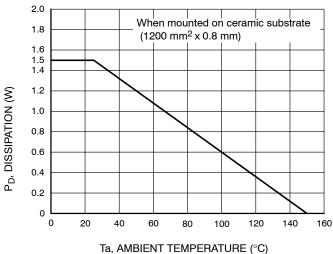
#### MCH6341

#### TYPICAL CHARACTERISTICS (continued)



5 8 9 10 Qg, TOTAL GATE CHARGE (nC) Figure 10. V<sub>GS</sub> - Qg





-3

-2

-1

0

0 1 2

Figure 12. P<sub>D</sub> - Ta





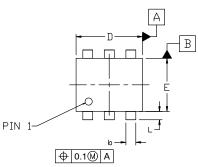
#### SC-88FL / MCPH6 CASE 419AS **ISSUE A**

**DATE 28 SEP 2022** 

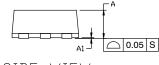
#### NOTES:

- NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND THE BAR PROTRUSIONS.

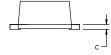
DIM	MILLIMETERS			
ואונע	MIN.	N□M.	MAX.	
Α	0.80	0.85	0.90	
A1	0.00		0.02	
b	0.25	0.30	0.40	
C	0.12	0.15	0.25	
D	1.94	2.00	2.06	
E	1.54	1.60	1.66	
He	2.05	2.10	2.15	
L	0.19	0.25	0.31	
L1	0.00	0.07	0.12	
е		0.65 BSC	)	

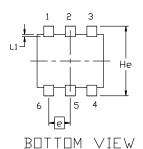












FRONT VIEW

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code М = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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